# V30D60CL

Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.34$  V at  $I_F = 5$  A



FEAT	U	RES	
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- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D60CL	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	A	
	per diode		15		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	200	А	
Voltage rate of change (rated $V_R$ )		dV/dt	10 000	V/µs	
Operating junction and storage temperature ra	nge	T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

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PRIMARY CHARACTERISTICS $I_{F(AV)}$ 2 x 15 A $V_{RRM}$ 60 V $I_{FSM}$ 200 A $V_F$  at  $I_F = 15 A$ 0.49 V $T_J$  max.150 °CPackageTO-263AC (SMPD)Diode variationsDual common cathode

RoHS COMPLIANT HALOGEN





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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 5 A$	T <sub>A</sub> = 25 °C	- V <sub>F</sub> (1)	0.44	-	V
	I <sub>F</sub> = 7.5 A			0.47	-	
	I <sub>F</sub> = 15 A			0.55	0.61	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 7.5 A			0.37	-	
	I <sub>F</sub> = 15 A			0.49	0.57	
Reverse current per diode	V <sub>B</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	4000	μA
	$v_{\rm R} = 00 v$	T <sub>A</sub> = 125 °C	'R (=/	35	110	mA

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V30D60CL	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	1.8	°C/W	
	per device		0.9		
	per device	R <sub>0JA</sub> <sup>(1)(2)</sup>	45		

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

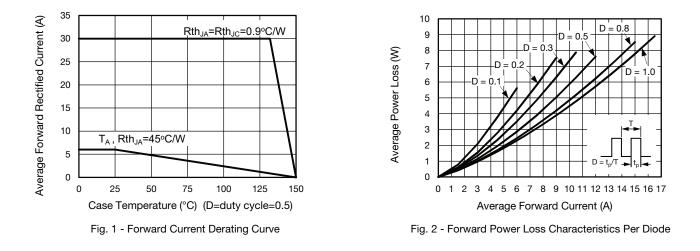
<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V30D60CL-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D60CLHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D60CLHM3_A/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)



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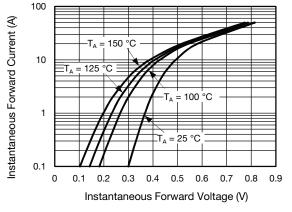
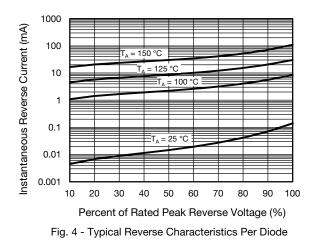


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



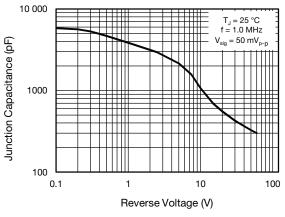


Fig. 5 - Typical Junction Capacitance Per Diode

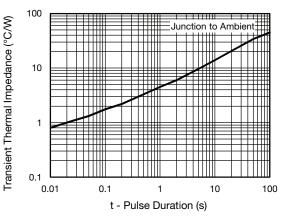
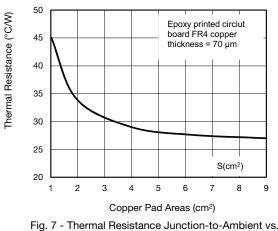


Fig. 6 - Typical Transient Thermal Impedance Per Diode



Copper Pad Areas

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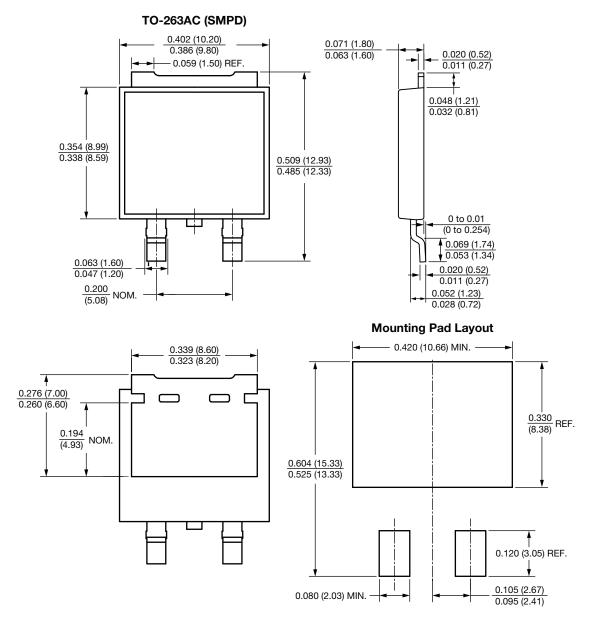
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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